

Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- Low power loss and soft switching
- High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of parts in built-in control circuit



Maximum ratings and characteristics

- Absolute maximum ratings (at $T_c=25^\circ\text{C}$ unless otherwise specified)

Item	Symbol	Rating		Unit		
		Min.	Max.			
Bus voltage	DC	V_{DC}	0	450	V	
	Surge	$V_{DC(surge)}$	0	500	V	
	Short operating	V_{sc}	200	400	V	
Collector-Emitter voltage *1		V_{CES}	0	600	V	
Inverter	Collector current	DC	I_C	-	50	A
		1ms	I_{CP}	-	100	A
		Duty=76.1% *2	$-I_C$	-	50	A
Collector power dissipation	One transistor *3	P_C	-	144	W	
Collector current	DC	I_C	-	30	A	
		1ms	I_{CP}	-	60	A
	Forward current diode	I_F	-	30	A	
	Collector power dissipation	One transistor *3	P_C	-	144	W
Supply voltage of Pre-Driver *4		V_{CC}	-0.5	20	V	
Input signal voltage *5		V_{in}	-0.5	$V_{CC}+0.5$	V	
Input signal current		I_{in}	-	3	mA	
Alarm signal voltage *6		V_{ALM}	-0.5	V_{CC}	V	
Alarm signal current *7		I_{ALM}	-	20	mA	
Junction temperature		T_j	-	150	$^\circ\text{C}$	
Operating case temperature		T_{opr}	-20	100	$^\circ\text{C}$	
Storage temperature		T_{stg}	-40	125	$^\circ\text{C}$	
Solder temperature *8		T_{sol}	-	260	$^\circ\text{C}$	
Isolating voltage (Terminal to base, 50/60Hz sine wave 1min.)		V_{iso}	-	AC2500	V	
Screw torque	Mounting (M5)		-	3.5	N·m	

Note

*1 : V_{ces} shall be applied to the input voltage between terminal P and U or ,u or W, N and U or V or W

*2 : $125^\circ\text{C}/\text{FWD } R_{th(j-c)} / (I_C \times V_F \text{ MAX}) = 125 / 1.263 / (50 \times 2.6) \times 100 = 76.1\%$

*3 : $P_C = 125^\circ\text{C}/\text{IGBT } R_{th(j-c)} = 125 / 0.87 = 144\text{W}$ [Inverter]

$P_C = 125^\circ\text{C}/\text{IGBT } R_{th(j-c)} = 125 / 0.87 = 144\text{W}$ [Breake]

*4 : V_{CC} shall be applied to the input voltage between terminal No.4 and 1, 8 and 5, 12 and 9, 14 and 13

*5 : V_{in} shall be applied to the input voltage between terminal No.3 and 1, 7 and 5, 11 and 9, 16,17,18 and 13.

*6 : V_{ALM} shall be applied to the voltage between terminal No.2 and 1, No6 and 5, No10 and 9, No.19 and 13.

*7 : I_{ALM} shall be applied to the input current to terminal No.2,6,10 and 19.

*8 : Immersion time $10 \pm 1\text{sec}$.

Electrical characteristics (at $T_c=T_j=25^\circ\text{C}$, $V_{cc}=15\text{V}$ unless otherwise specified.)

● Main circuit

Item		Symbol	Condition	Min.	Typ.	Max.	Unit	
Inverter	Collector current at off signal input	ICES	$V_{CE}=600\text{V}$ V_{in} terminal open.	-	-	1.0	mA	
	Collector-Emitter saturation voltage	$V_{CE(sat)}$	Ic=50A	Terminal	-	-	2.5	V
				Chip	-	2.0	-	
	Forward voltage of FWD	V_F	-Ic=50A	Terminal	-	-	2.6	V
Chip				-	1.6	-		
Brake	Collector current at off signal input	ICES	$V_{CE}=600\text{V}$ V_{in} terminal open.	-	-	1.0	mA	
	Collector-Emitter saturation voltage	$V_{CE(sat)}$	Ic=30A	Terminal	-	-	2.2	V
				Chip	-	1.75	-	
	Forward voltage of Diode	V_F	-Ic=30A	Terminal	-	-	3.3	V
Chip				-	1.9	-		
Turn-on time	ton	$V_{DC}=300\text{V}, T_j=125^\circ\text{C}$		1.2	-	-	μs	
Turn-off time	toff	IC=50A Fig.1, Fig.6		-	-	3.6		
Reverse recovery time	trr	$V_{DC}=300\text{V}, I_C=50\text{A}$ Fig.1, Fig.6		-	-	0.3		
Maximum Avalanche Energy (A non-repetition)	PAV	Internal wiring inductance=50nH Main circuit wiring inductance=54nH		30	-	-	mJ	

● Control circuit

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Supply current of P-line side pre-driver(one unit)	I _{ccp}	Switching Frequency : 0 to 15kHz $T_c=-20$ to 125°C Fig.7	-	-	18	mA
Supply current of N-line side pre-driver	I _{ccn}		-	-	65	mA
Input signal threshold voltage (on/off)	$V_{in(th)}$	ON	1.00	1.35	1.70	V
		OFF	1.25	1.60	1.95	V
Input zener voltage	V_Z	$R_{in}=20\text{k}\Omega$	-	8.0	-	V
Alarm signal hold time	t _{ALM}	$T_c=-20^\circ\text{C}$ Fig.2	1.1	-	-	ms
		$T_c=25^\circ\text{C}$ Fig.2	-	2.0	-	ms
		$T_c=125^\circ\text{C}$ Fig.2	-	-	4.0	ms
Current limit resistor	R _{ALM}	Alarm terminal	1425	1500	1575	ohm

● Protection Section ($V_{cc}=15\text{V}$)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Over Current Protection Level of Inverter circuit	I _{oc}	$T_j=125^\circ\text{C}$	75	-	-	A
Over Current Protection Level of Brake circuit	I _{oc}	$T_j=125^\circ\text{C}$	45	-	-	A
Over Current Protection Delay time	t _{DOC}	$T_j=125^\circ\text{C}$	-	5	-	μs
SC Protection Delay time	t _{SC}	$T_j=125^\circ\text{C}$ Fig.4	-	-	8	μs
IGBT Chip Over Heating	T_{jOH}	Surface of IGBT chips	150	-	-	$^\circ\text{C}$
Over Heating Protection Hysteresis	T_{jH}		-	20	-	$^\circ\text{C}$
Under Voltage Protection Level	V_{UV}		11.0	-	12.5	V
Under Voltage Protection Hysteresis	V_H		0.2	0.5	-	V

● Thermal characteristics($T_c=25^\circ\text{C}$)

Item			Symbol	Min.	Typ.	Max.	Unit
Junction to Case thermal resistance *9	Inverter	IGBT	R _{th(j-c)}	-	-	0.87	$^\circ\text{C/W}$
		FWD	R _{th(j-c)}	-	-	1.263	$^\circ\text{C/W}$
	Brake	IGBT	R _{th(j-c)}	-	-	0.87	$^\circ\text{C/W}$
Case to fin thermal resistance with compound			R _{th(c-f)}	-	0.05	-	$^\circ\text{C/W}$

*9 For 1 device, Case is under the device

● Noise Immunity ($V_{DC}=300\text{V}$, $V_{cc}=15\text{V}$, Test Circuit Fig.5)

Item	Condition	Min.	Typ.	Max.	Unit
Common mode rectangular noise	Pulse width 1 μs , polarity \pm , 10minuets Judge : no over-current, no miss operating	± 2.0	-	-	kV
Common mode lightning surge	Rise time 1.2 μs , Fall time 50 μs Interval 20s, 10 times Judge : no over-current, no miss operating	± 5.0	-	-	kV

● Recommendable value

Item	Symbol	Min.	Typ.	Max.	Unit
DC Bus Voltage	V_{DC}	-	-	400	V
Operating Supply Voltage of Pre-Driver	V_{CC}	13.5	15.0	16.5	V
Screw torque (M5)	-	2.5	-	3.0	Nm

● Weight

Item	Symbol	Min.	Typ.	Max.	Unit
Weight	Wt	-	270	-	g

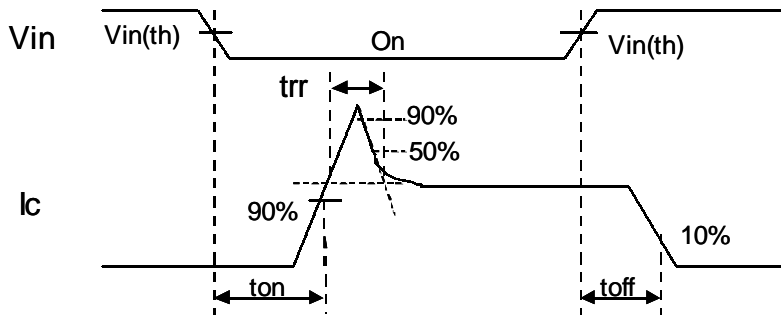
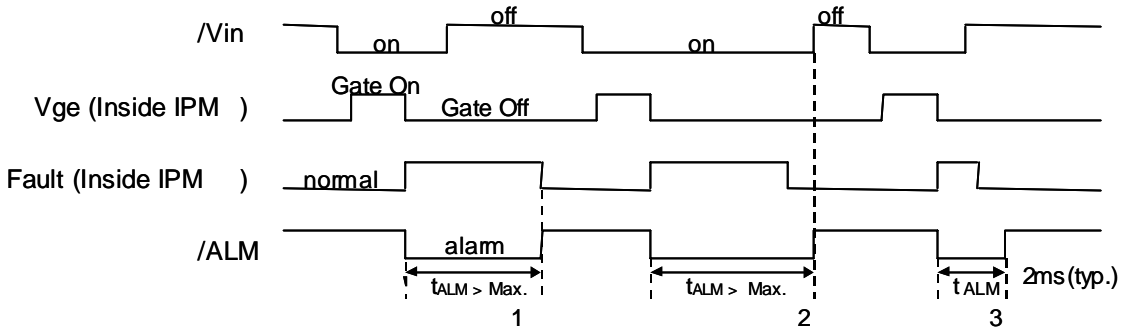


Figure 1. Switching Time Waveform Definitions



Fault : Over-current, Over-heat or Under-voltage

Figure 2. Input/Output Timing Diagram

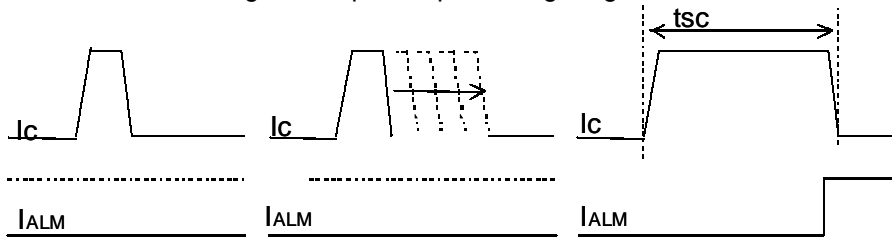


Figure.4 Definition of tsc

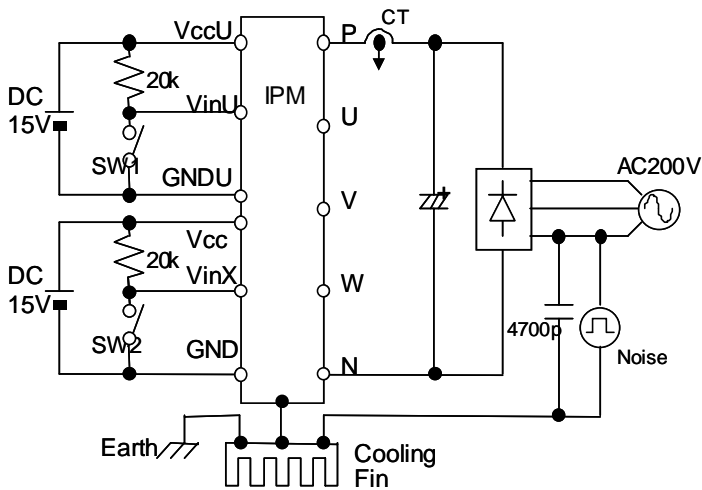


Figure 5. Noise Test Circuit

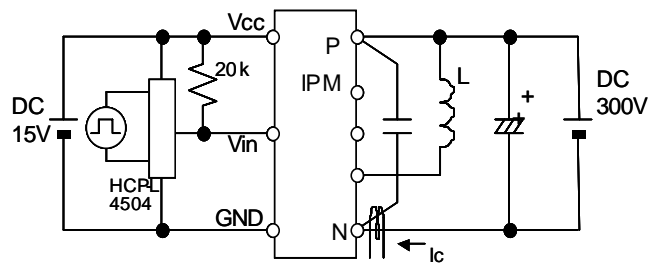


Figure 6. Switching Characteristics Test Circuit

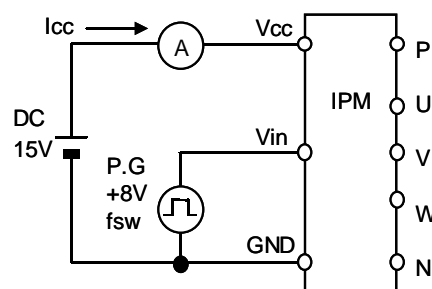
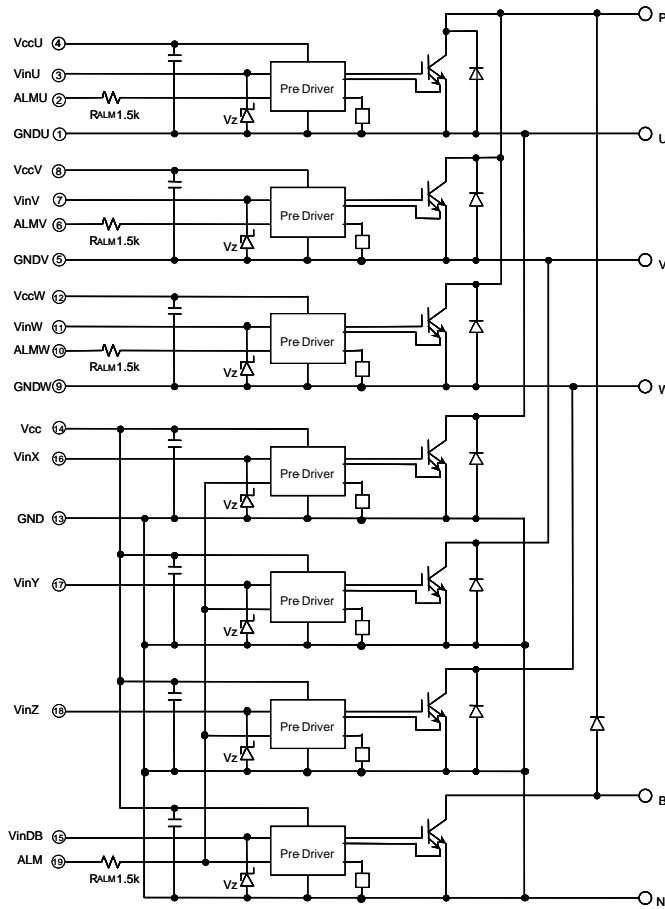


Figure 7. Icc Test Circuit

Block diagram

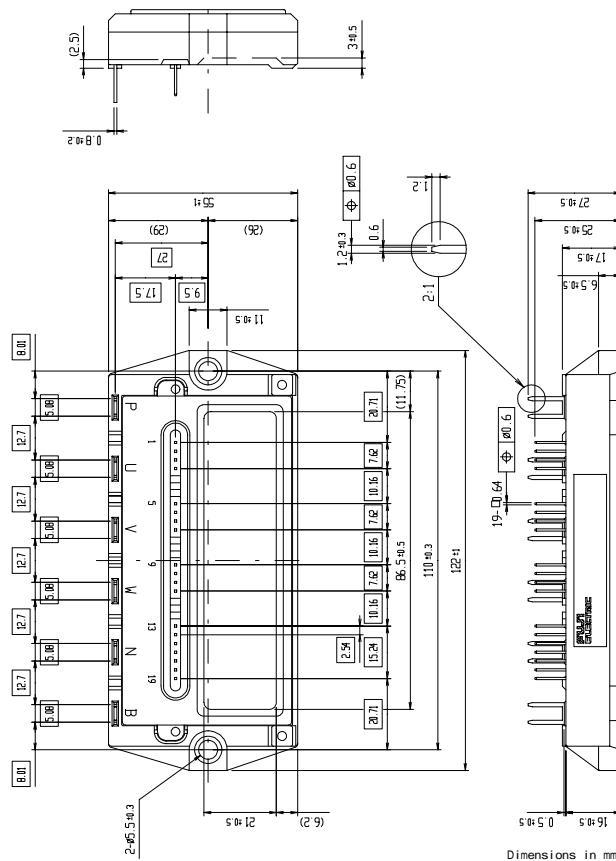


Pre-drivers include following functions

1. Amplifier for driver
2. Short circuit protection
3. Under voltage lockout circuit
4. Over current protection
5. IGBT chip over heating protection

Outline drawings, mm

Package type : P622

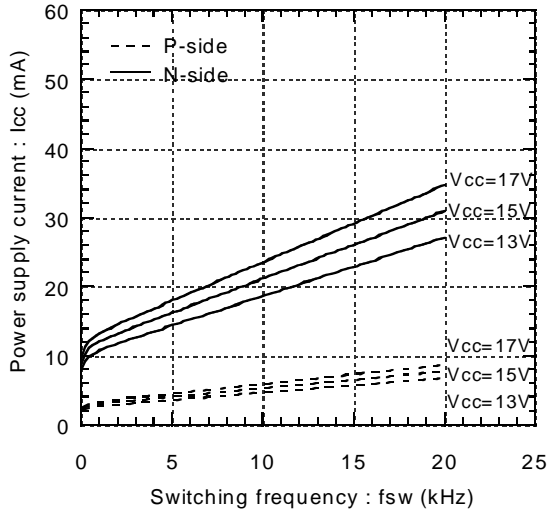


Mass : 270g

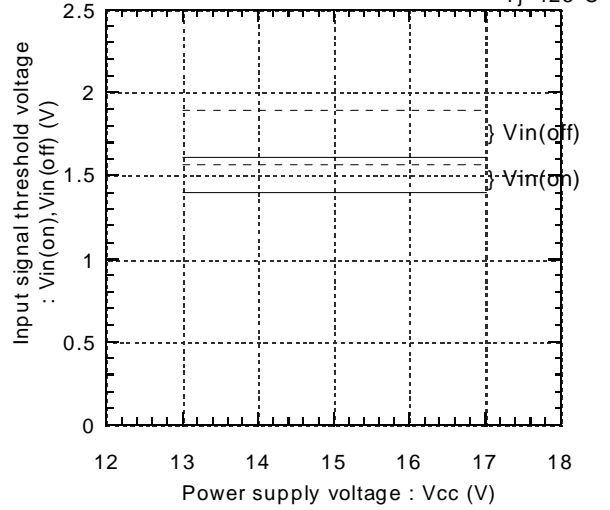
Characteristics

Control circuit characteristics (Representative)

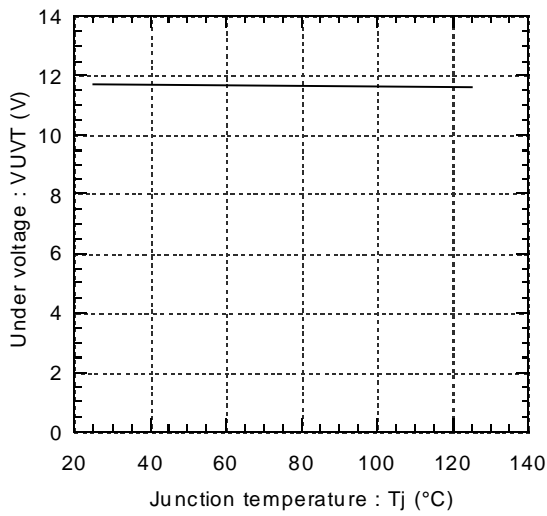
Power supply current vs. Switching frequency
Tc=125°C



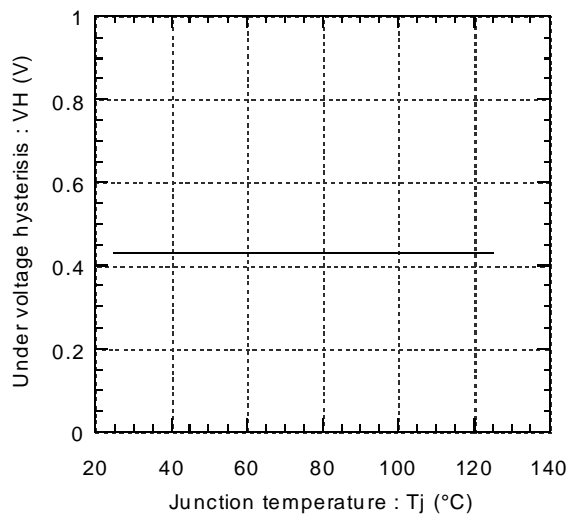
Input signal threshold voltage vs. Power supply voltage



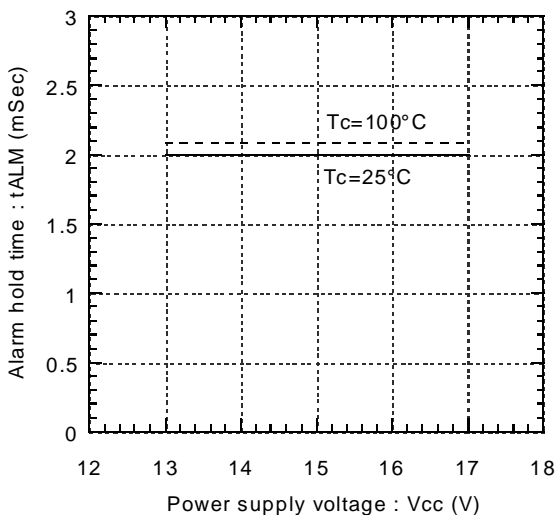
Under voltage vs. Junction temperature



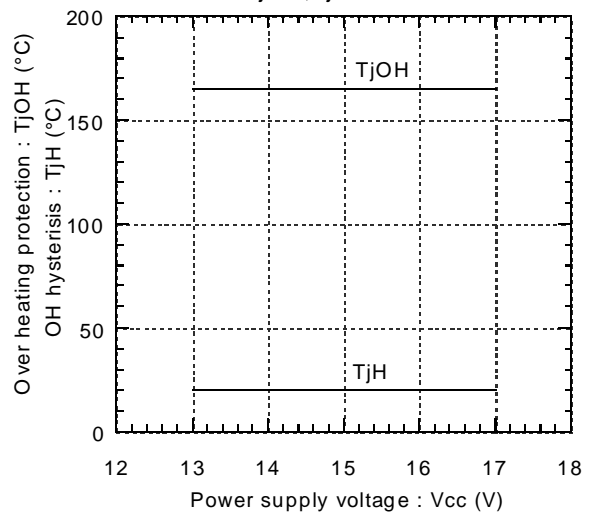
Under voltage hysteresis vs. Junction temperature



Alarm hold time vs. Power supply voltage

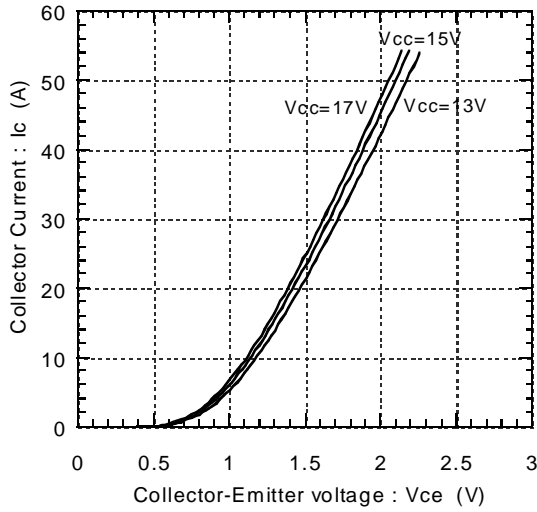


Over heating characteristics
TjOH, TjH vs. Vcc

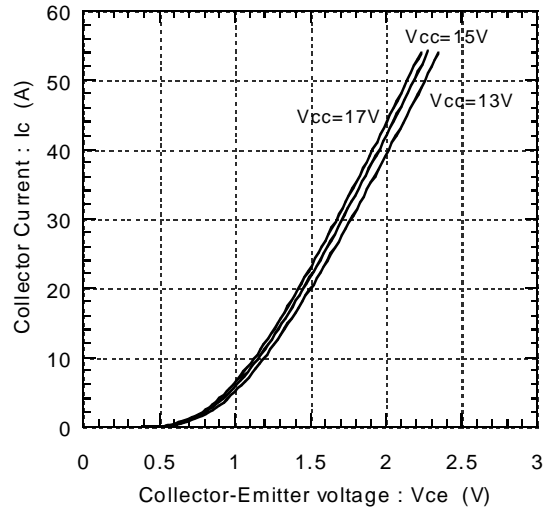


● Main circuit characteristics (Representative)

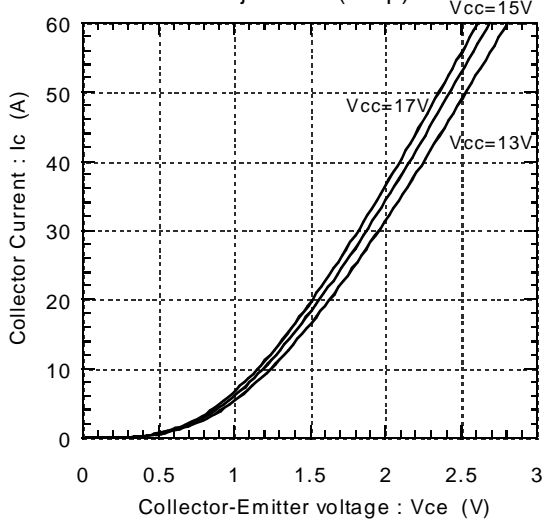
Collector current vs. Collector-Emitter voltage
Tj=25°C(Chip)



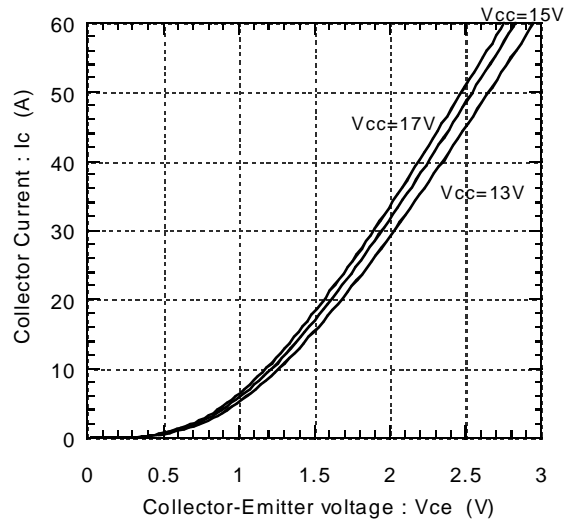
Collector current vs. Collector-Emitter voltage
Tj=25°C(Terminal)



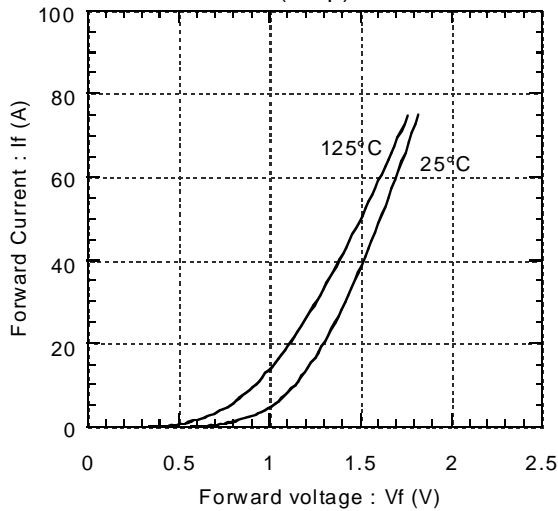
Collector current vs. Collector-Emitter voltage
Tj=125°C(Chip)



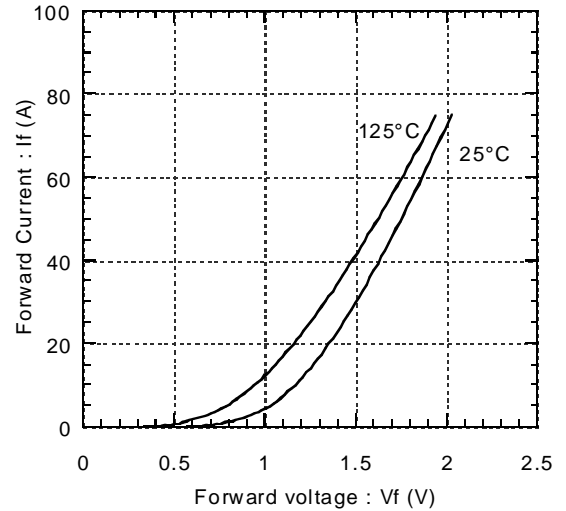
Collector current vs. Collector-Emitter voltage
Tj=125°C(Terminal)

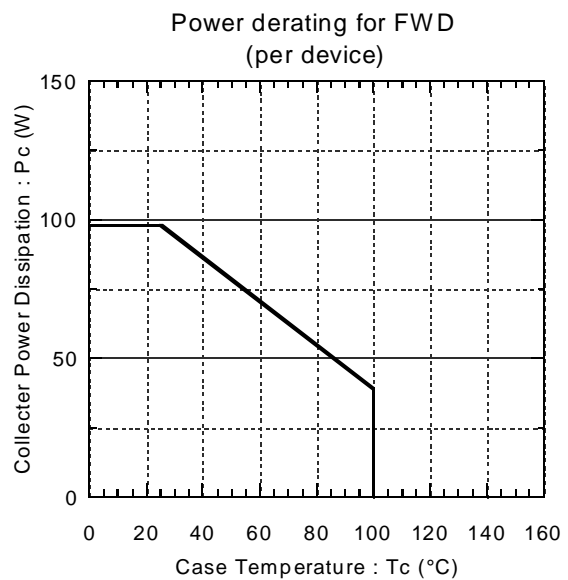
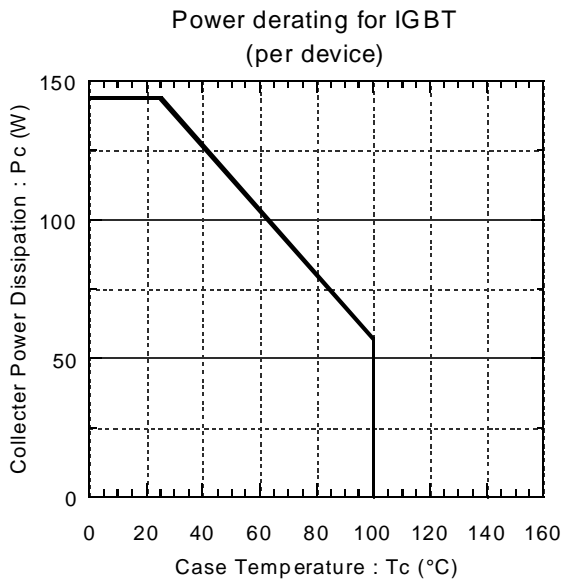
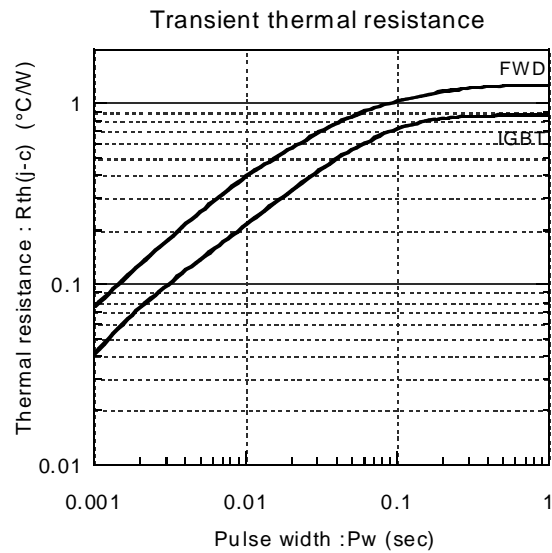
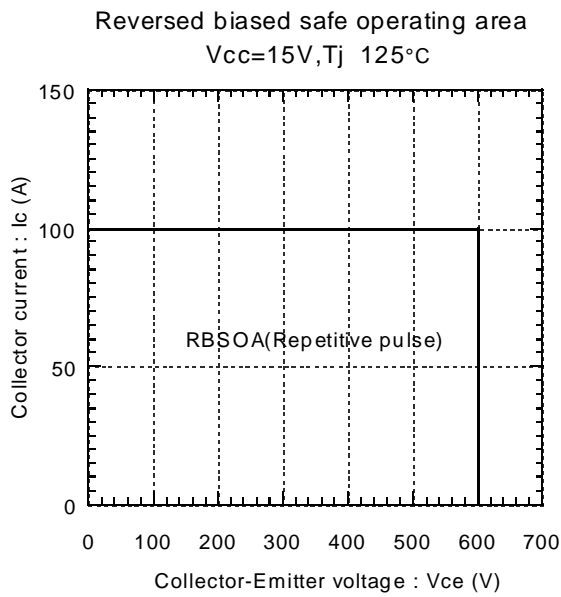
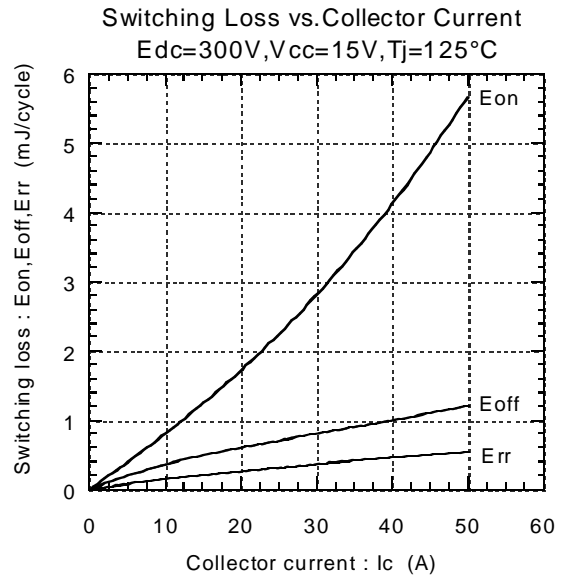
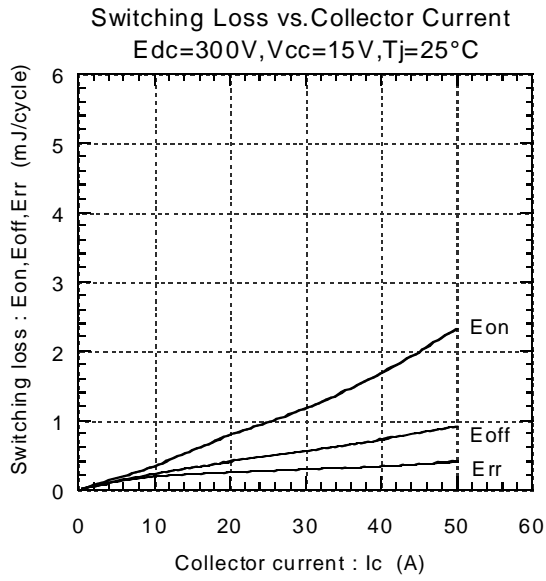


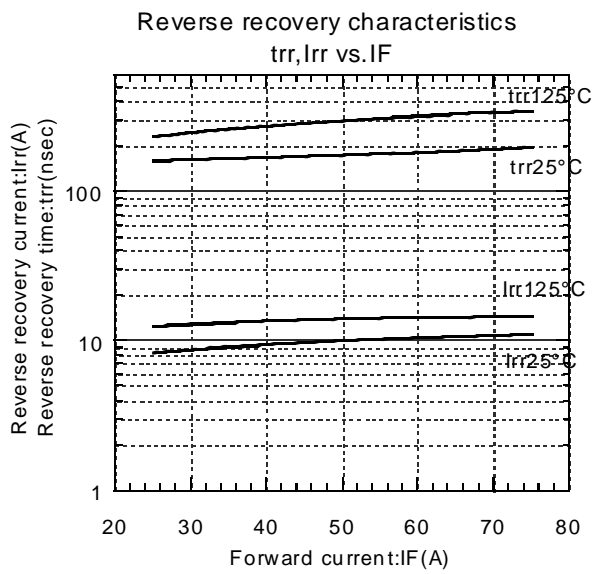
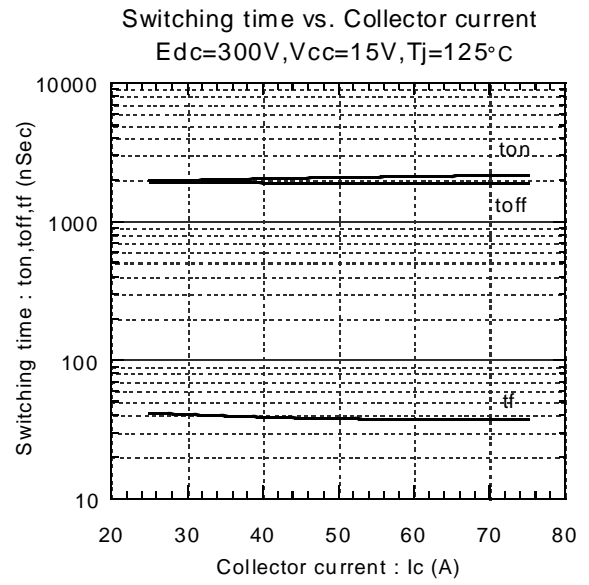
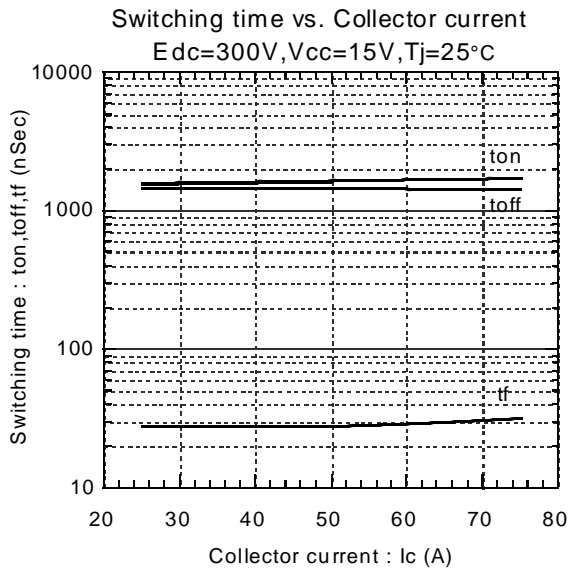
Forward current vs. Forward voltage
(Chip)



Forward current vs. Forward voltage
(Terminal)



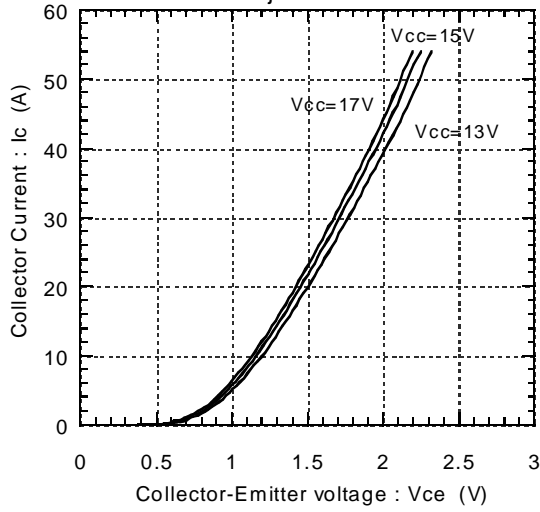




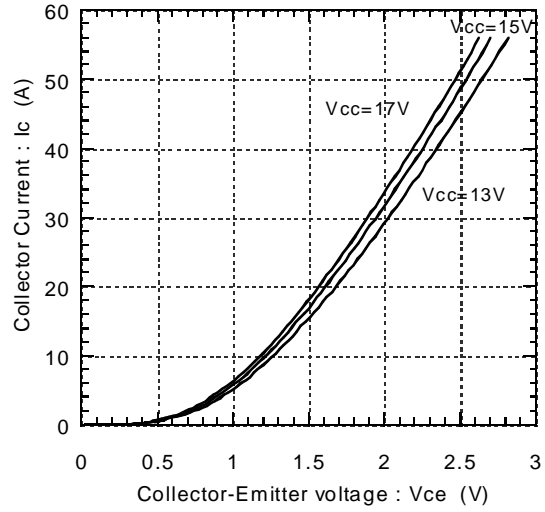
■ Characteristics

● Dynamic Brake Characteristics (Representative)

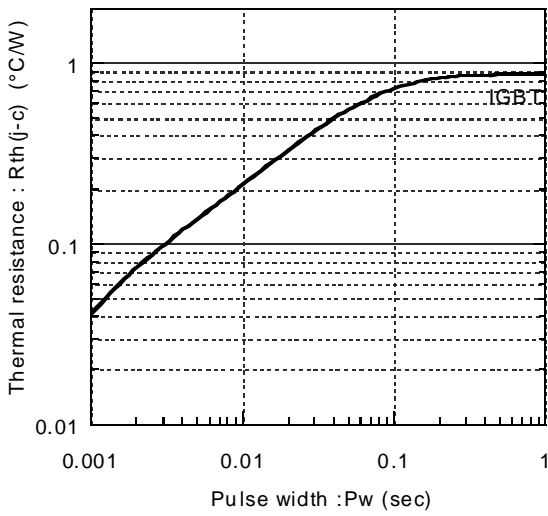
Collector current vs. Collector-Emmitter voltage
T_j=25°C



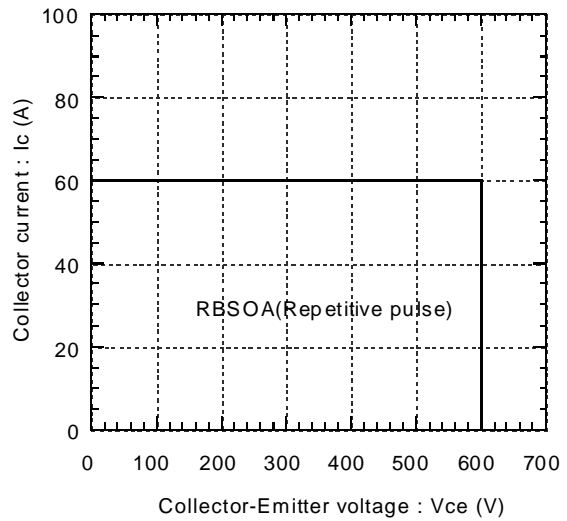
Collector current vs. Collector-Emmitter voltage
T_j=125°C



Transient thermal resistance



Reversed biased safe operating area
V_{cc}=15V, T_j 125°C



Power derating for IGBT
(per device)

